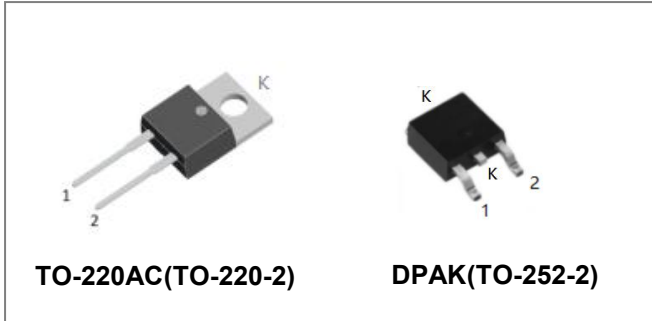


## S4D02120A S4D02120E 1200V SiC POWER SCHOTTKY RECTIFIERS



### Description

S4D02120A/S4D02120E are SiC Schottky rectifiers packaged in TO-220AC(TO-220-2)/DPAK(TO-252-2) case. The devices are high voltage Schottky rectifiers that have very low total conduction losses and very stable switching characteristics over temperature extremes. The S4D02120A/S4D02120E are ideal for energy sensitive, high frequency applications in challenging environments.

### Circuit Diagram



### Features

- 175°C T<sub>J</sub> operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

### Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

### Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	1200	V
Average Rectified Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>c</sub> =150°C, rectangular wave form	2	A
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	10ms, Half Sine pulse, T <sub>J</sub> =25°C	44	A
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	10 ms, Half Sine pulse, T <sub>J</sub> =25°C	13	A

### Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 2A, Pulse, T <sub>J</sub> = 25 °C	1.5	1.8	V
	V <sub>F2</sub>	@ 2A, Pulse, T <sub>J</sub> = 175 °C	1.9	3.0	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.5	10	uA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 175 °C	1.2	15	uA
Junction Capacitance	C <sub>T</sub>	VR=0V, T <sub>J</sub> =25°C, f=1MHz	116	-	pF

\* Pulse width < 300 μs, duty cycle < 2%

### Thermal-Mechanical Specifications:

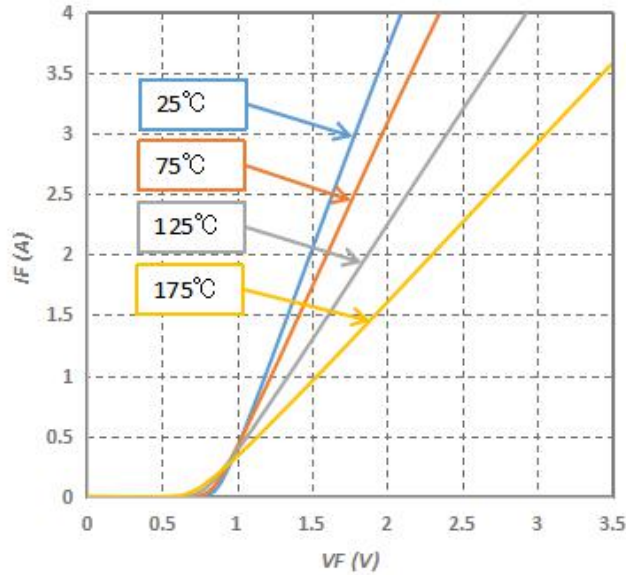
Characteristics	Symbol	S4D02120A	S4D02120E	Units
Junction Temperature	T <sub>J</sub>	-55 to +175		°C
Storage Temperature	T <sub>stg</sub>	-55 to +175		°C
Maximum Thermal Resistance Junction to Case	R <sub>qJC</sub>	1.7	1.5	°C/W

### Ordering Information

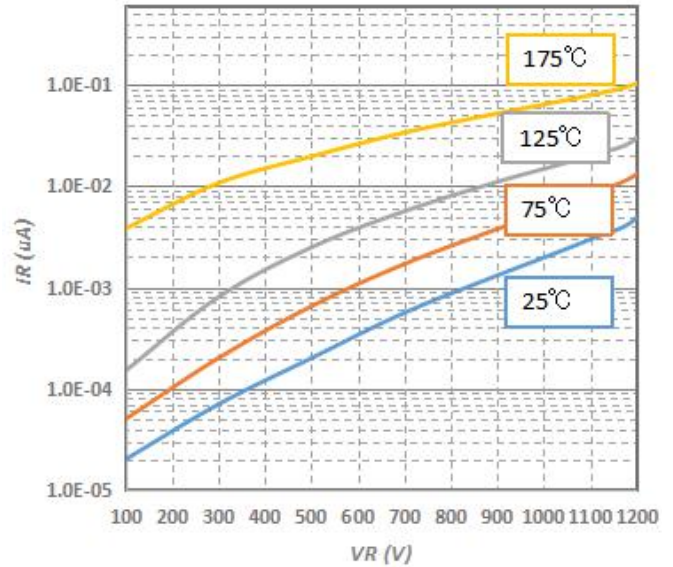
Device	Package	Shipping
S4D02120A	TO-220AC(TO-220-2)	50pcs / tube
S4D02120E	DPAK(TO-252-2)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

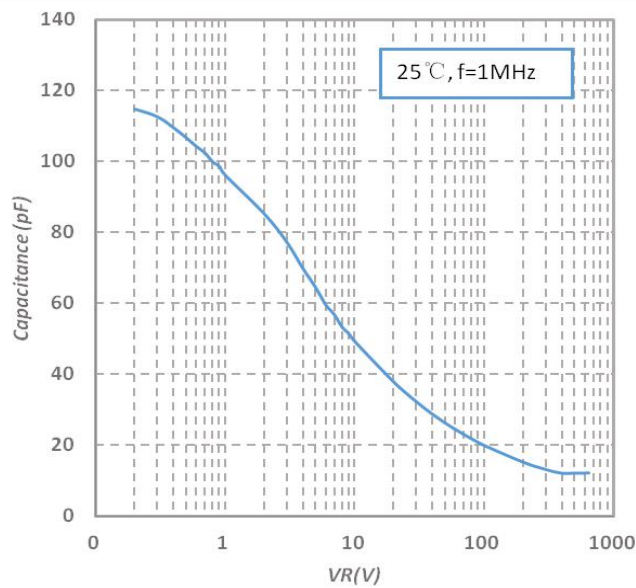
**Ratings and Characteristics Curves**



**Fig.1-Typical Forward Voltage Characteristics**

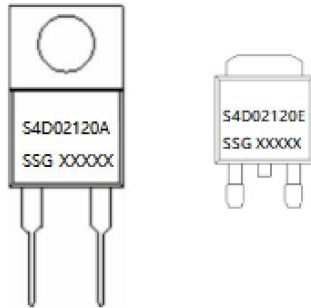


**Fig.2-Typical Reverse Characteristics**



**Fig.3-Capacitance vs. Reverse Voltage**

## Marking Diagram

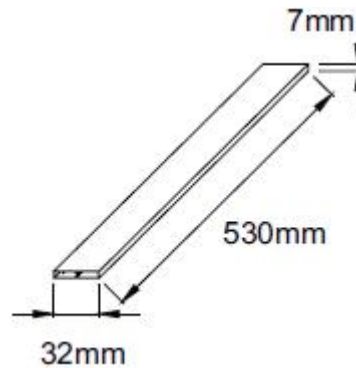


Where XXXXX is YYWWL

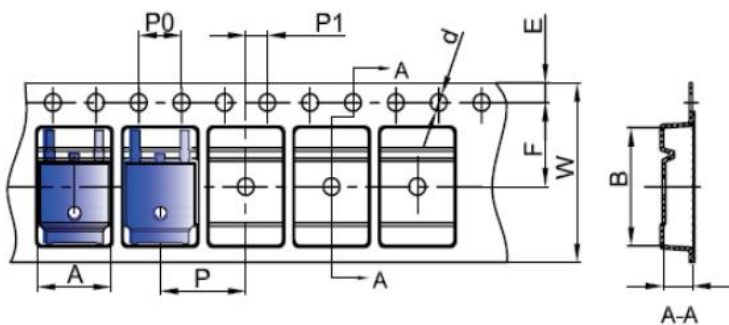
S4D = Device Type  
A/E = Package type  
02 = Forward Current (2A)  
120 = Reverse Voltage (1200V)  
SSG = SSG  
YY = Year  
WW = Week  
L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

## Tube Specification(TO-220-2)

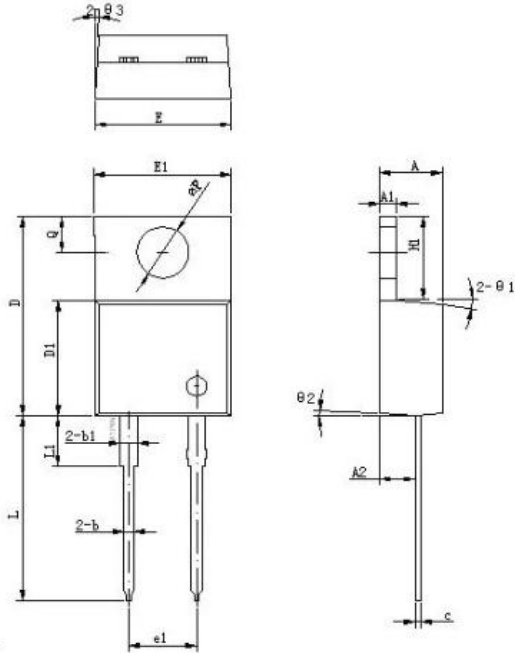


## Carrier Tape & Reel Specification DPAK(TO-252-2)



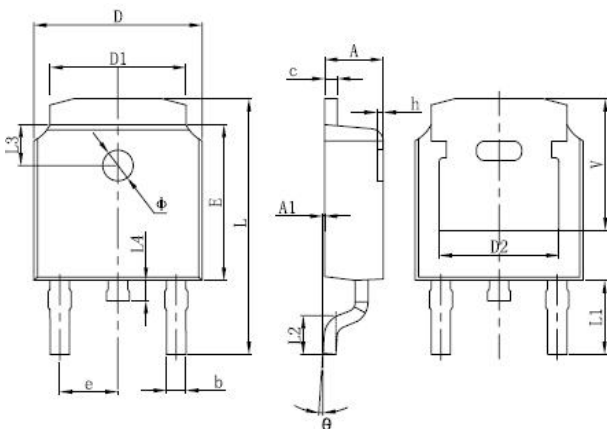
SYMBOL	Millimeters	
	Min.	Max.
A	6.80	7.00
B	10.40	10.60
C	2.60	2.80
d	Φ1.45	Φ1.65
E	1.65	1.85
F	7.40	7.60
P0	3.90	4.10
P	7.90	8.10
P1	1.90	2.10
W	15.90	16.30

**Mechanical Dimensions TO-220AC(TO-220-2)**



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.55	4.70	4.85
A1	1.17	1.27	1.37
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1		1.27	
c	0.36	0.38	0.61
D	14.64	14.94	15.24
D1	8.55	8.70	8.90
E	10.01	10.16	10.31
E1	9.98	10.18	10.38
e1		5.08	
H1	6.04	6.24	6.44
L	13.00	13.86	14.08
L1		3.80	
ΦP	3.74	3.84	4.04
Q	2.54	2.74	2.94
Θ1		5°	
Θ2		4°	
Θ3		4°	

**Mechanical Dimensions DPAK(TO-252-2)**



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.40	0.086	0.094
A1	0	0.13	0	0.005
b	0.635	0.889	0.025	0.035
c	0.460	0.889	0.018	0.035
D	6.50	6.70	0.250	0.265
D1	4.95	5.46	0.195	0.215
D2	4.32 REF.		0.170 REF.	
E	6.00	6.20	0.235	0.245
e	2.286 BSC		0.090 BSC	
L	9.398	10.414	0.370	0.410
L1	1.778 REF.		0.108 REF.	
L2	1.40	1.78	0.055	0.07
L3	1.60 REF.		0.063 REF.	
L4	0.60	1.02	0.024	0.040
Φ	1.10	1.30	0.043	0.051
Θ	0°	10°	0°	10°
h	0	0.30	0	0.012
V	5.21 REF.		0.205 REF.	



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